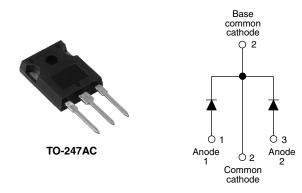


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Schottky Rectifier, 2 x 30 A



PRODUCT SUMMARY							
Package	TO-247AC						
I _{F(AV)}	2 x 30 A						
V _R	100 V						
V _F at I _F	0.64 V						
I _{RM} max.	25 mA at 125 °C						
T _J max.	175 °C						
Diode variation	Common cathode						
E _{AS}	15 mJ						

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- · Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-63CPQ100... center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I _{F(AV)}	Rectangular waveform	60	А							
V _{RRM}		100	V							
I _{FSM}	t _p = 5 μs sine	2200	А							
V _F	30 Apk, T _J = 125 °C (per leg)	0.64	V							
TJ	Range	- 55 to 175	°C							

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-63CPQ100PbF	VS-63CPQ100-N3	UNITS					
Maximum DC reverse voltage	V _R	100	100	V					
Maximum working peak reverse voltage	V _{RWM}	100	100	v					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS				
Maximum average per leg		50 % duty cycle at T _C = 153 °C, rectangular waveform		30					
See fig. 5 per device	I _{F(AV)}	30% duty cycle at $T_{\rm C} = 133$ C	, rectangular wavelonn	60	A				
Maximum peak one cycle non-repetitive surge current per leg	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	2200					
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	410					
Non-repetitive avalanche energy per leg	on-repetitive avalanche energy per leg E_{AS} $T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 30 \text{ mH}$		15	mJ					
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim		1	А				

Revision: 31-Aug-11

Document Number: 94244

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ELECTRICAL SPECIFICATIO	NS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		30 A	T _{.1} = 25 °C	0.77		
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	60 A	1j=25 C	0.92	V	
See fig. 1	VFM (")	30 A	T 105 %C	0.64		
		60 A	T _J = 125 °C	0.76		
Maximum reverse leakage current per leg	I _{BM} ⁽¹⁾	T _J = 25 °C	V - Poted V	0.3	mA	
See fig. 2	IRM (")	T _J = 125 °C	$V_R = Rated V_R$	25		
Threshold voltage	V _{F(TO)}	T T maximum	·	0.38	V	
Forward slope resistance	r _t	T _J = T _J maximum		5.75	mΩ	
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range	1300	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 m	Measured lead to lead 5 mm from package body			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

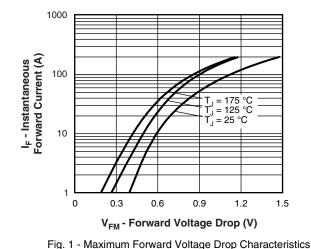
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	BOL TEST CONDITIONS		UNITS				
Maximum junction and storage temperature range	1	T _J , T _{Stg}		- 55 to 175	°C				
Maximum thermal resistance, junction to case per leg		Р	DC operation See fig. 4	0.8					
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation		°C/W				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.25					
				6	g				
Approximate weight				0.21	oz.				
Mounting torque	minimum			6 (5)	kgf ⋅ cm				
Mounting torque —	maximum			12 (10)	(lbf · in)				
Marking device			Case style TO-247AC (JEDEC)	63CP	Q100				



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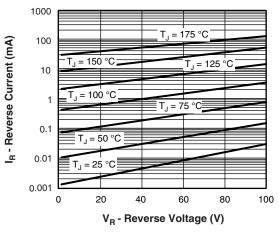


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

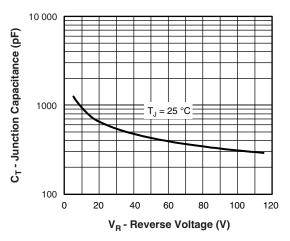


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

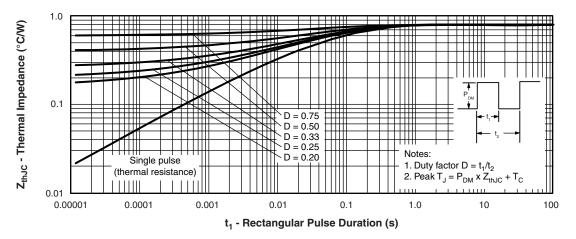
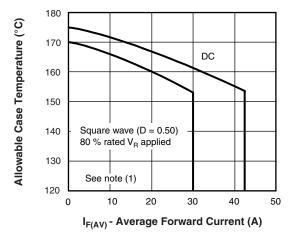
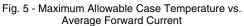


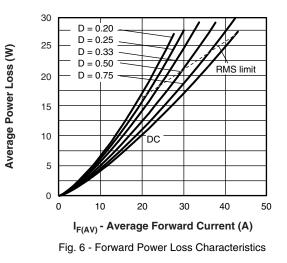
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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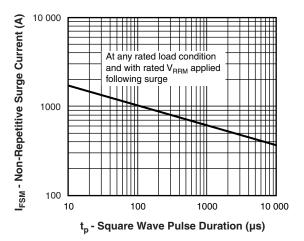


Fig. 7 - Maximum Non-Repetitive Surge Current

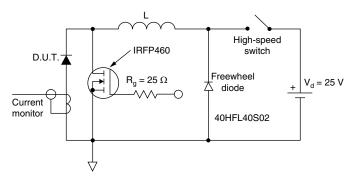


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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ORDERING INFORMATION TABLE

Device code	vs-	63	С	Р	Q	100	PbF
		2	3	4	5	6	7
	1 - 2 - 3 - 4 - 5 - 6 - 7 -	Cur Circ C = Pac P = Sch Volt Env • F	rent ratii uit confi Commo kage: TO-247 ottky "Q age coo ironmer bF = Le	" series le ntal digit ead (Pb)	.) i: de -free and	d RoHS	•
		• -	N3 = Ha	logen-fr	ee, RoH	IS comp	oliant, a

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-63CPQ100PbF	25	500	Antistatic plastic tube						
VS-63CPQ100-N3	25	500	Antistatic plastic tube						

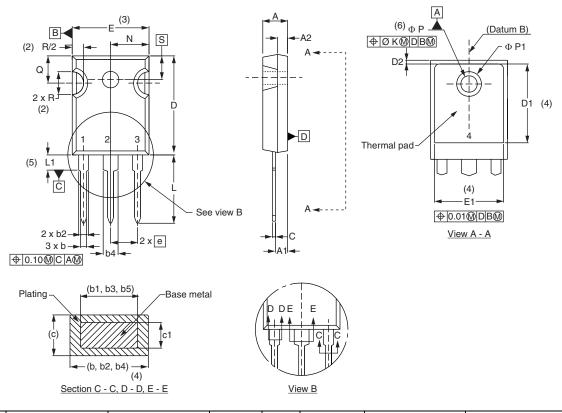
LINKS TO RELATED DOCUMENTS								
Dimensions		www.vishay.com/doc?95223						
Port marking information	TO-247AC PbF	www.vishay.com/doc?95226						
Part marking information	TO-247AC -N3	www.vishay.com/doc?95007						



Vishay Semiconductors

TO-247

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098			E1	13.72	-	0.540	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053			ØК	2.	54	0.0	010	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			N	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	' BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension c

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